

MGBR20S50

Preliminary

DIODE

MOS GATED BARRIER RECTIFIER

DESCRIPTION

The UTC **MGBR20S50** is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed etc.

The UTC MGBR20S50 suitable for supply applications.

FEATURES

* Super low forward voltage drop

* High switching speed

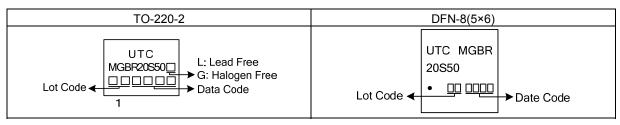
SYMBOL

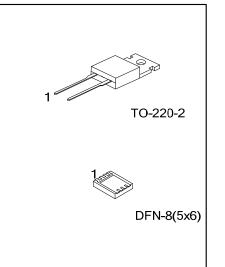
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ORDERING INFORMATION

Ordering Number		Package	Pin Assignment							Decking	
Lead Free	Lead Free Halogen Free		1	2	3	4	5	6	7	8	Packing
MGBR20S50L-TA2-T	-TA2-T MGBR20S50G-TA2-T		κ	А	-	-	-	-	-	-	Tube
- MGBR20S50G-K08-5060-R		DFN-8(5×6)	А	А	Α	NC	Κ	κ	κ	κ	Tape Reel
Note: Pin Assignment: A: Anode K: Cathode											
MGBR20S50 <u>L-TA2-T</u> (1)Packing Type		(1) T: Tube, R: Tape Reel									
	(2)Package Type	(2) TA2: TO-220-2, K08-5060: DFN-8(5×6)									
(3)Green Package (3) L: Lead Free, G: Halogen Free and Lead Free						ee					

MARKING





Preliminary

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%

Tor capacitance load, derate current by 2070.			
PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	V _{RM}	50	V
Working Peak Reverse Voltage	V _{RWM}	50	V
Peak Repetitive Reverse Voltage	V _{RRM}	50	V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% Duty Cycle	Ιο	20	А
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	300	А
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I _{RRM}	2	А
Maximum Rate of Voltage Change (at Rated V_R)	dv/dt	10000	V/µS
Operating Junction Temperature	TJ	-65~+150	°C
Storage Junction Temperature	T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
hungting to Americant	TO-220-2	0	°0044	
Junction to Ambient	DFN-8(5×6)	θ _{JA}	72	°C/W

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA	50			V
Forward Voltage		I _F =20A, TJ=25°C			0.53	V
		I⊧=20A, T」=125°C			0.48	V
Reverse Current (Note 1)	DM	V _R =50V, T _J =25°C			500	μA
		V _R =50V, T _J =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



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